

0~+3w

22.1%

Power tolerance

Maximum efficiency

# 605W-630W

High efficiency monocrystal silicon double-sided half solar panel

## Double glass glass



#### Multiple primary gate (N-type) technology

Effectively improve optical utilization and reduce internal current loss



#### PID resistance

Excellent PID tolerance at 96 hours (85 ° C /85%)



#### Resistance to cracking

Apply innovative non-destructive cutting technology to reduce the risk of cracking



#### The module efficiency is up to 22.1%

The half-cell structure has a higher lifetime power generation capacity with low resistance characteristics



#### **HOT3.0 Technology**

Shorter current transmission distance, less resistance loss, higher battery efficiency



#### Double sided power generation

The double-sided generation gain on the back side is increased by light, significantly reducing the LCOE



#### **High reliability**

The anti-PID performance is improved through battery process optimization and material control



#### Higher customer value

Industry leading technology and power warranty to ensure long-term efficient performance of components



#### High power generation performance

The unique version design brings stronger resistance to shadow occlusion. The power generation is large.



#### Authentication certificates

EC61215、IEC61730、CE、CQC

- · 1S08001:2015: Quality management system
- · 18014001:2015: Environmental management system
- · 1S045001:2018: Occupational health and safety management













# 605W-630W

### **Goosun Energy Construction Group Co., Ltd.**

#### **Electrical specifications**

Maximum power PMAX	605W	610W	615W	620W	625W	630W
Open circuit voltage (Voc)	40.31	40.46	40.60	40.74	40.88	41.02
Short circuit current (Isc/A)	15.90	15.96	16.02	16.08	16.14	16.20
Maximum power voltage (Vmpp)	43.35	43.53	43.71	43.88	44.06	44.23
Maximum power of current	15.01	15.08	15.15	15.22	15.29	15.36
Module efficiency (%)	22.4%	22.6%	22.8%	23.0%	23.1%	23.3%
Power tolerance (W)			0~+3			

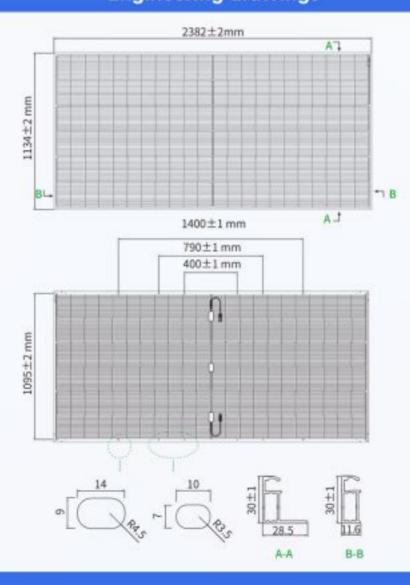
STC: light intensity 1000W/m, battery temperature 25°C, air quality 5.

Test conditions: irradiance 800W/m, ambient temperature 20°C, wind speed 1m/s.

#### Mechanical specifications

Battery type	N	I-type monocrystalline silicon solar cell		
Number of battery cells		132片		
size		2382*1134*30mm		
Weight	eight 32.4kg			
Glass	2.0mm high penetration coated toughened gla			
Framework		Anodized aluminum alloy		
Junction box		Protection level IP68		
Output cable		4mm length 300mm or customized		
Connector type		JK03M/MC4		

#### **Engineering drawings**



#### Temperature characteristics

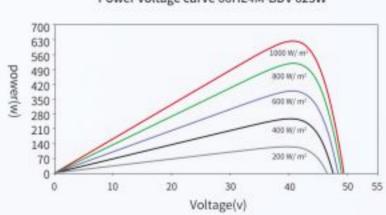
NOCT temperature	-40°C+70°C	
Temperature coefficient (PMAX)	-0.290%/°C	
Temperature coefficient (VOC)	-0.250%/°C	
Temperature coefficient (ISC)	0.045%°C	

#### Maximum rated parameters

Maximum system voltage (IEC)	1500VDC	
Snow/wind	5400Pa/2400Pa	
Operating temperature	-40°C~+85°C	
Maximum series fuse rating	35A	

#### L-V curve

Power voltage curve 66HL4M-BDV 625W



Current voltage curve 66HL4M-BDV 625W

